

International  
**IR** Rectifier

ST700C..L SERIES

PHASE CONTROL THYRISTORS

Hockey Puk Version

#### Features

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AC (B-PUK)

910A

#### Typical Applications

- DC motor control
- Controlled DC power supplies
- AC controllers

case style TO-200AC (B-PUK)

#### Major Ratings and Characteristics

Parameters	ST700C..L	Units
$I_{T(AV)}$	910	A
@ $T_{hs}$	55	°C
$I_{T(RMS)}$	1857	A
@ $T_{hs}$	25	°C
$I_{TSM}$	15700	A
@ 60Hz	16400	A
$I^2t$	1232	KA <sup>2</sup> s
@ 60Hz	1125	KA <sup>2</sup> s
$V_{DRM}/V_{RRM}$	1200 to 2000	V
$t_q$ typical	150	μs
$T_J$	- 40 to 125	°C

## ST700C..L Series

Bulletin I25190 rev. D 04/00

International  
**IR** Rectifier

### ELECTRICAL SPECIFICATIONS

#### Voltage Ratings

Type number	Voltage Code	$V_{DRM}/V_{RRM}$ , max. repetitive peak and off-state voltage V	$V_{RSM}$ , maximum non-repetitive peak voltage V	$I_{DRM}/I_{RRM}$ max. @ $T_J = T_{J\max}$ mA
ST700C..L	12	1200	1300	80
	16	1600	1700	
	18	1800	1900	
	20	2000	2100	

#### On-state Conduction

Parameter	ST700C..L	Units	Conditions
$I_{T(AV)}$ Max. average on-state current @ Heatsink temperature	910 (355)	A	180° conduction, half sine wave
	55 (85)	°C	double side (single side) cooled
$I_{T(RMS)}$ Max. RMS on-state current	1857	A	DC @ 25°C heatsink temperature double side cooled
$I_{TSM}$ Max. peak, one-cycle non-repetitive surge current	15700		t = 10ms No voltage reapplied
	16400		t = 8.3ms
	13200		t = 10ms 100% $V_{RRM}$ reapplied
	13800		t = 8.3ms reapplied
$I^2t$ Maximum $I^2t$ for fusing	1232	KA <sup>2</sup> s	Sinusoidal half wave, Initial $T_J = T_{J\max}$ .
	1125		t = 10ms No voltage reapplied
	871		t = 8.3ms
	795		t = 10ms 100% $V_{RRM}$ reapplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	12321	KA <sup>2</sup> /s	t = 0.1 to 10ms, no voltage reapplied
$V_{T(TO)1}$ Low level value of threshold voltage	1.00	V	(16.7% $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$ ), $T_J = T_{J\max}$ .
$V_{T(TO)2}$ High level value of threshold voltage	1.13		( $I > \pi \times I_{T(AV)}$ ), $T_J = T_{J\max}$ .
$r_{t1}$ Low level value of on-state slope resistance	0.40	mΩ	(16.7% $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$ ), $T_J = T_{J\max}$ .
$r_{t2}$ High level value of on-state slope resistance	0.35		( $I > \pi \times I_{T(AV)}$ ), $T_J = T_{J\max}$ .
$V_{TM}$ Max. on-state voltage	1.80	V	$I_{pk} = 2000A$ , $T_J = T_{J\max}$ , $t_p = 10ms$ sine pulse
$I_H$ Maximum holding current	600	mA	$T_J = 25^\circ C$ , anode supply 12V resistive load
$I_L$ Typical latching current	1000		

### Switching

Parameter	ST700C..L	Units	Conditions
di/dt	Max. non-repetitive rate of rise of turned-on current	1000	A/μs
t <sub>d</sub>	Typical delay time	1.0	μs
t <sub>q</sub>	Typical turn-off time	150	I <sub>TM</sub> = 750A, T <sub>j</sub> = T <sub>j</sub> max, di/dt = 60A/μs, V <sub>R</sub> = 50V dv/dt = 20V/μs, Gate 0V 100Ω, t <sub>p</sub> = 500μs

### Blocking

Parameter	ST700C..L	Units	Conditions
dv/dt	Maximum critical rate of rise of off-state voltage	500	V/μs
I <sub>DRM</sub> / <sub>RRM</sub>	Max. peak reverse and off-state leakage current	80	mA

### Triggering

Parameter	ST700C..L	Units	Conditions
P <sub>GM</sub>	Maximum peak gate power	10.0	
P <sub>G(AV)</sub>	Maximum average gate power	2.0	
I <sub>GM</sub>	Max. peak positive gate current	3.0	A
+V <sub>GM</sub>	Maximum peak positive gate voltage	20	
-V <sub>GM</sub>	Maximum peak negative gate voltage	5.0	V
I <sub>GT</sub>	DC gate current required to trigger	TYP. 200 100 50	mA
V <sub>GT</sub>	DC gate voltage required to trigger	MAX. - 200 3.0 -	
I <sub>GD</sub>	DC gate current not to trigger	10	mA
V <sub>GD</sub>	DC gate voltage not to trigger	0.25	V

T<sub>j</sub> = T<sub>j</sub> max, t<sub>p</sub> ≤ 5ms  
 T<sub>j</sub> = T<sub>j</sub> max, f = 50Hz, d% = 50  
 T<sub>j</sub> = T<sub>j</sub> max, t<sub>p</sub> ≤ 5ms  
 T<sub>j</sub> = T<sub>j</sub> max, t<sub>p</sub> ≤ 5ms  
 T<sub>j</sub> = -40°C  
 T<sub>j</sub> = 25°C  
 T<sub>j</sub> = 125°C  
 T<sub>j</sub> = -40°C  
 T<sub>j</sub> = 25°C  
 T<sub>j</sub> = 125°C  
 T<sub>j</sub> = T<sub>j</sub> max

Max. required gate trigger/ current/voltage are the lowest value which will trigger all units 12V anode-to-cathode applied  
 Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated V<sub>DRM</sub> anode-to-cathode applied

## ST700C..L Series

Bulletin I25190 rev. D 04/00

International  
**IR** Rectifier

### Thermal and Mechanical Specification

Parameter	ST700C..L	Units	Conditions
$T_J$	Max. operating temperature range	-40 to 125	$^{\circ}\text{C}$
$T_{\text{stg}}$	Max. storage temperature range	-40 to 150	
$R_{\text{thJ-hs}}$	Max. thermal resistance, junction to heatsink	0.073 0.031	K/W DC operation single side cooled DC operation double side cooled
$R_{\text{thC-hs}}$	Max. thermal resistance, case to heatsink	0.011 0.006	
F	Mounting force, $\pm 10\%$	14700 (1500)	N (Kg)
wt	Approximate weight	255	g
Case style	TO - 200AC (B-PUK)	See Outline Table	

### $\Delta R_{\text{thJ-hs}}$ Conduction

(The following table shows the increment of thermal resistance  $R_{\text{thJ-hs}}$  when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.009	0.009	0.006	0.006	K/W	$T_J = T_{\text{J max.}}$
120°	0.011	0.011	0.011	0.011		
90°	0.014	0.014	0.015	0.015		
60°	0.020	0.020	0.021	0.021		
30°	0.036	0.036	0.036	0.036		

### Ordering Information Table

Device Code									
1	ST	70	0	C	20	L	1		
1		2	3	4	5	6	7	8	
<b>1</b>	- Thyristor								
<b>2</b>	- Essential part number								
<b>3</b>	- 0 = Converter grade								
<b>4</b>	- C = Ceramic Puk								
<b>5</b>	- Voltage code: Code x 100 = $V_{\text{RRM}}$ (See Voltage Rating Table)								
<b>6</b>	- L = Puk Case TO-200AC (B-PUK)								
<b>7</b>	- 0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads) 1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads) 2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads) 3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads)								
<b>8</b>	- Critical dv/dt: None = 500V/ $\mu\text{sec}$ (Standard selection) L = 1000V/ $\mu\text{sec}$ (Special selection)								

Outline Table

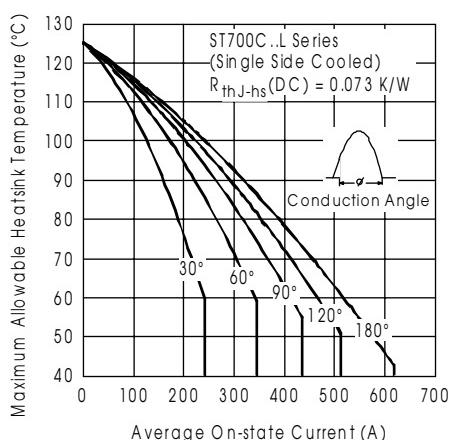
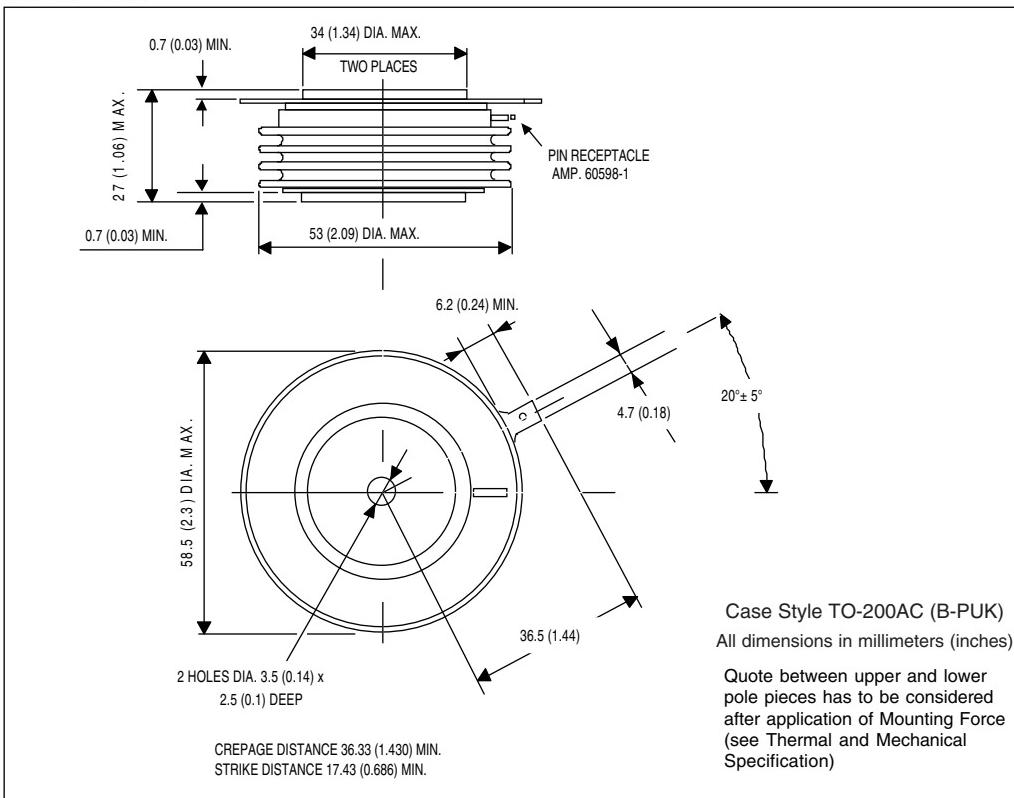


Fig. 1 - Current Ratings Characteristics

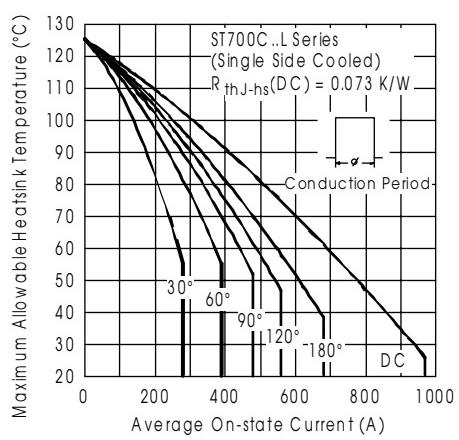


Fig. 2 - Current Ratings Characteristics

## ST700C..L Series

Bulletin I25190 rev. D 04/00

International  
**IR** Rectifier

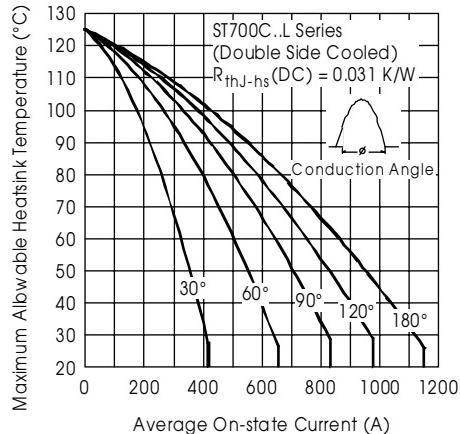


Fig. 3 - Current Ratings Characteristics

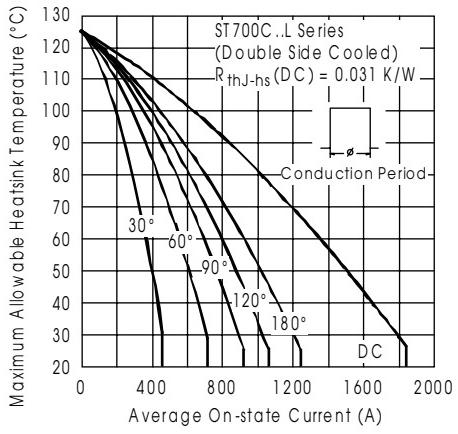


Fig. 4 - Current Ratings Characteristics

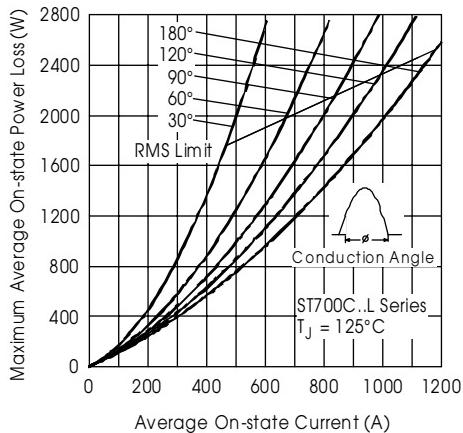


Fig. 5 - On-state Power Loss Characteristics

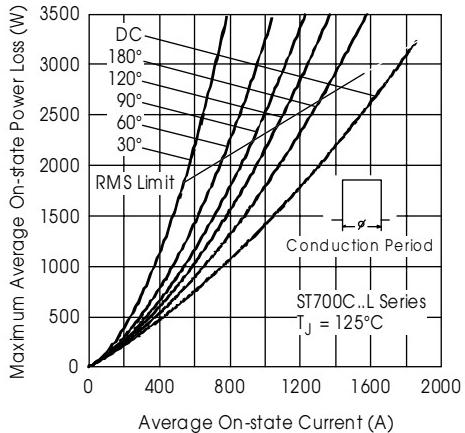


Fig. 6 - On-state Power Loss Characteristics

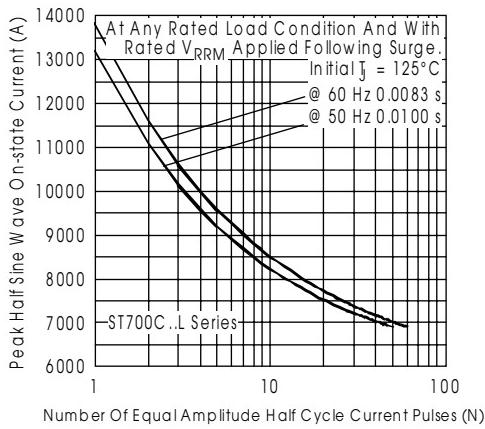


Fig. 7 - Maximum Non-Repetitive Surge Current  
Single and Double Side Cooled

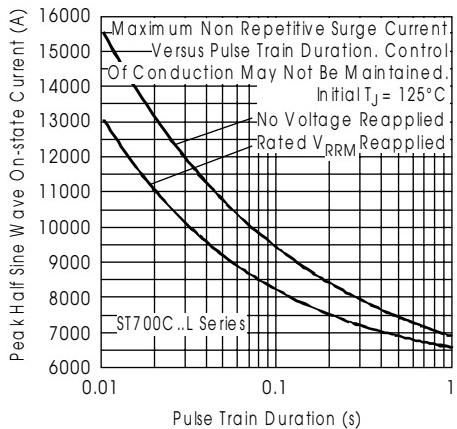


Fig. 8 - Maximum Non-Repetitive Surge Current  
Single and Double Side Cooled

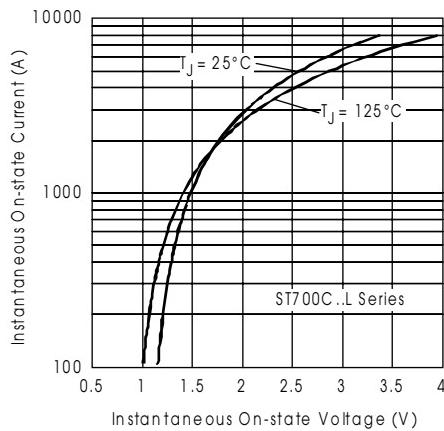


Fig. 9 - On-state Voltage Drop Characteristics

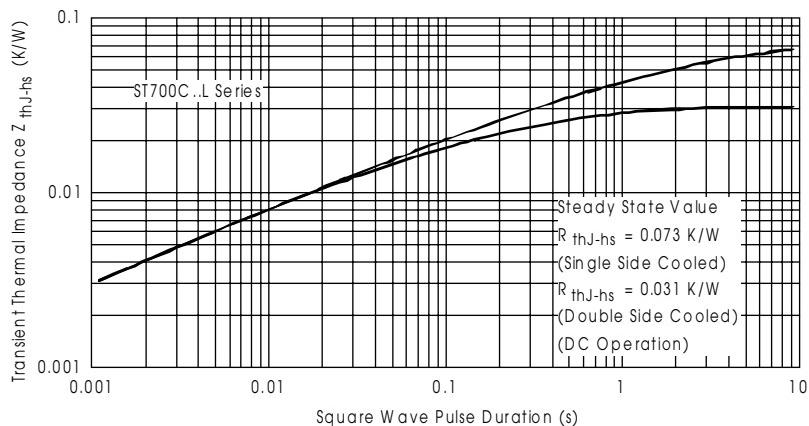


Fig. 10 - Thermal Impedance  $Z_{thJ-hs}$  Characteristics

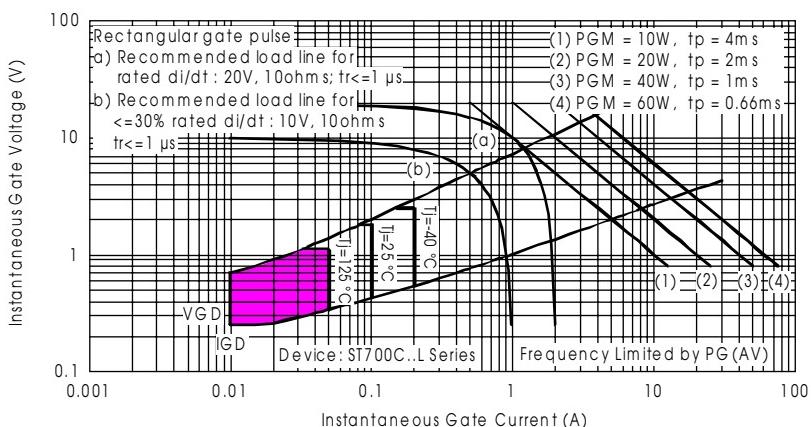


Fig. 11 - Gate Characteristics